PN2907ABU Datasheet

DiGi Electronics Part Number	PN2907ABU-DG
Manufacturer	onsemi
Manufacturer Product Number	PN2907ABU
Description	TRANS PNP 60V 0.8A TO92-3
Detailed Description	Bipolar (BJT) Transistor PNP 60 V 800 mA 200MHz 625 mW Through Hole TO-92-3

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Tel: +00 852-30501935

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
PN2907ABU	onsemi
Series:	Product Status:
-	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	800 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ Ib, Ic:
60 V	1.6V @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
20nA (ICBO)	100 @ 150mA, 10V
Power - Max:	Frequency - Transition:
625 mW	200MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-226-3, TO-92-3 (TO-226AA)	TO-92-3
Base Product Number:	
PN2907	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	Not Applicable
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0075	

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PN2907A / MMBT2907A / PZT2907A
60 V PNP General-Purpose Transistor

Features

- High DC Current Gain (h_{FE}) Range: 100 ~ 300
- High-Current Gain Bandwidth Product (f_T): 200 MHz (Minimum)
- Maximum Turn-On Time (t_{on}): 45 ns
- Maximum Turn-Off Time (t_{off}): 100 ns
- Ultra-Small Surface-Mount Package: SOT-223 (PZT2907A)

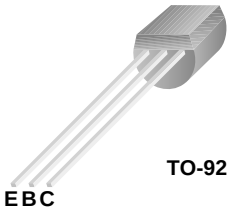
Applications

- General-Purpose Amplifier
- Switch

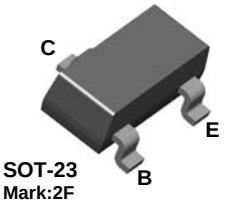
Description

The PN2907A, MMBT2907A, and PZT2907A are 60 V PNP bipolar transistors designed for use as a general-purpose amplifier or switch in applications that require up to 500 mA. Offered in an ultra-small surface-mount package (SOT-223), the PZT2907A is ideal for space-constrained systems. The NPN complementary types are the PN2222A, MMBT2222A, and PZT2222A; respectively.

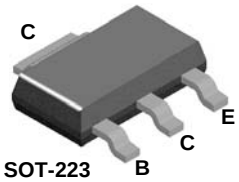
PN2907A



MMBT2907A



PZT2907A



Ordering Information

Part Number	Top Mark	Package	Packing Method
PN2907ABU	2907A	TO-92 3L	Bulk
PN2907ATF	2907A	TO-92 3L	Tape and Reel
PN2907ATFR	2907A	TO-92 3L	Tape and Reel
PN2907ATA	2907A	TO-92 3L	Ammo
PN2907ATAR	2907A	TO-92 3L	Ammo
MMBT2907A	2F	SOT-23 3L	Tape and Reel
MMBT2907A-D87Z	2F	SOT-23 3L	Tape and Reel
PZT2907A	2907A	SOT-223 4L	Tape and Reel

October-2017, Rev. 2

Publication Order Number:
PZT2907A/D

Absolute Maximum Ratings[1],[2]

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{CEO}	Collector-Emitter Voltage	-60	V
V_{CBO}	Collector-Base Voltage	-60	V
V_{EBO}	Emitter-Base Voltage	-5.0	V
I_C	Collector Current - Continuous	-800	mA
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C

Notes:

1. These ratings are based on a maximum junction temperature of 150°C.
2. These are steady-state limits. ON Semiconductor should be consulted on applications involving pulsed or low-duty cycle operations.

Thermal Characteristics

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Max.			Unit
		PN2907A[4]	MMBT2907A[3]	PZT2907A[4]	
P_D	Total Device Dissipation	625	350	1000	mW
	Derate Above 25°C	5.0	2.8	8.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

Notes:

3. Device is mounted on FR-4 PCB 1.6 inch X 1.6 inch X 0.06 inch.
4. PCB size: FR-4 76 x 114 x 1.57 mm^3 (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
Off Characteristics					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage[5]	I_C = -10 mA, I_B = 0	-60		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I_C = -10 μA, I_E = 0	-60		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I_E = -10 μA, I_C = 0	-5.0		V
I_{BL}	Base Cut-Off Current	V_{CE} = -30 V, V_{EB} = -0.5 V		-50	nA
I_{CEX}	Collector Cut-Off Current	V_{CE} = -30 V, V_{EB} = -0.5 V		-50	nA
I_{CBO}	Collector Cut-Off Current	V_{CB} = -50 V, I_E = 0		-0.02	μA
		V_{CB} = -50 V, I_E = 0, T_A = 150°C		-20	
On Characteristics					
h_{FE}	DC Current Gain	I_C = -0.1 mA, V_{CE} = -10 V	75		
		I_C = -1.0 mA, V_{CE} = -10 V	100		
		I_C = -10 mA, V_{CE} = -10 V	100		
		I_C = -150 mA, V_{CE} = -10 V[5]	100	300	
		I_C = -500 mA, V_{CE} = -10 V[5]	50		
V_{CE}(sat)	Collector-Emitter Saturation Voltage[5]	I_C = -150 mA, I_B = -15 mA		-0.4	V
		I_C = -500 mA, I_B = -50 mA		-1.6	
V_{BE}(sat)	Base-Emitter Saturation Voltage	I_C = -150 mA, I_B = -15 mA[5]		-1.3	V
		I_C = -500 mA, I_B = -50 mA		-2.6	
Small Signal Characteristics					
f_T	Current Gain - Bandwidth Product	I_C = -50 mA, V_{CE} = -20 V, f = 100 MHz	200		MHz
C_{ob}	Output Capacitance	V_{CB} = -10 V, I_E = 0, f = 100 kHz		8.0	pF
C_{ib}	Input Capacitance	V_{EB} = -2.0 V, I_C = 0, f = 100 kHz		30	pF
Switching Characteristics					
t_{on}	Turn-On Time	V_{CC} = -30 V, I_C = -150 mA, I_{B1} = -15 mA		45	ns
t_d	Delay Time			10	ns
t_r	Rise Time			40	ns
t_{off}	Turn-Off Time	V_{CC} = -6.0 V, I_C = -150 mA, I_{B1} = I_{B2} = -15mA		100	ns
t_s	Storage Time			80	ns
t_f	Fall Time			30	ns

Notes:

5. Pulse test: pulse width ≤ 300 μs, duty cycle ≤ 2.0%.

Typical Performance Characteristics

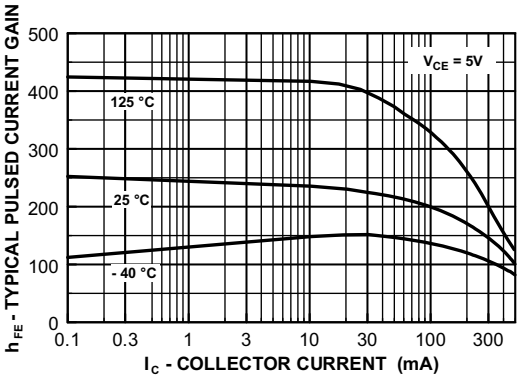


Figure 1. Typical Pulsed Current Gain vs. Collector Current

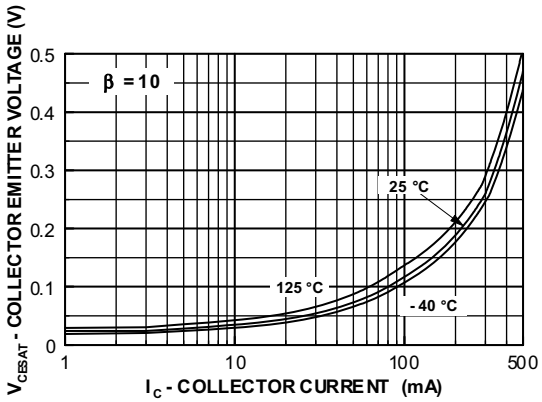


Figure 2. Collector-Emitter Saturation Voltage vs. Collector Current

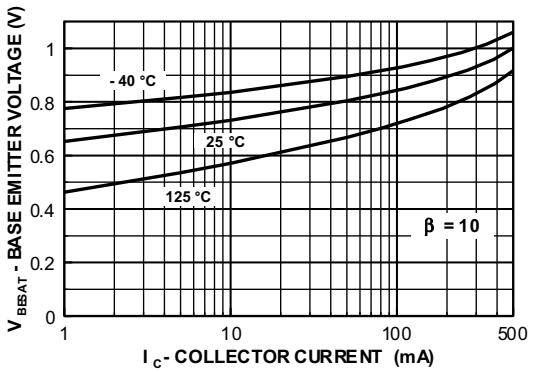


Figure 3. Base-Emitter Saturation Voltage vs. Collector Current

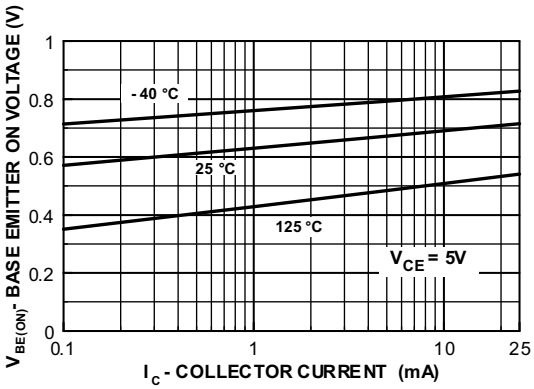


Figure 4. Base-Emitter On Voltage vs. Collector Current

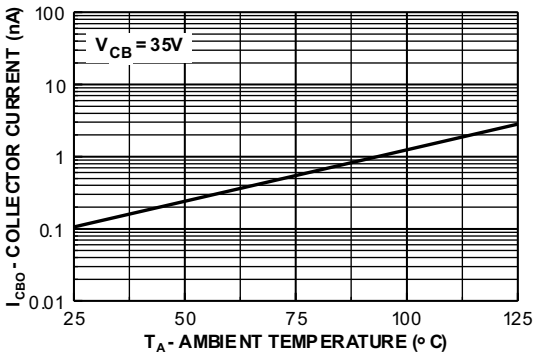


Figure 5. Collector Cut-Off Current vs. Ambient Temperature

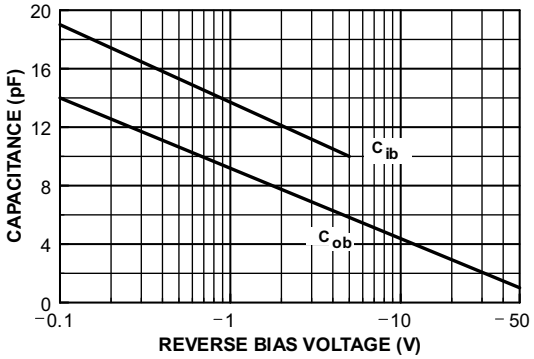


Figure 6. Input and Output Capacitance vs. Reverse Bias Voltage

Typical Performance Characteristics (Continued)

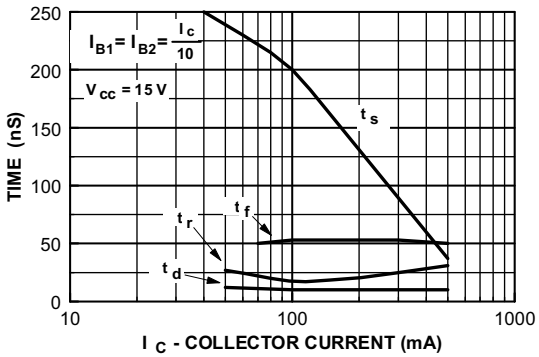


Figure 7. Switching Times vs. Collector Current

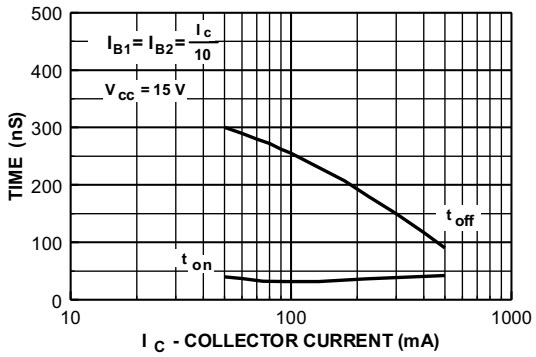


Figure 8. Turn-On and Turn-Off Times vs. Collector Current

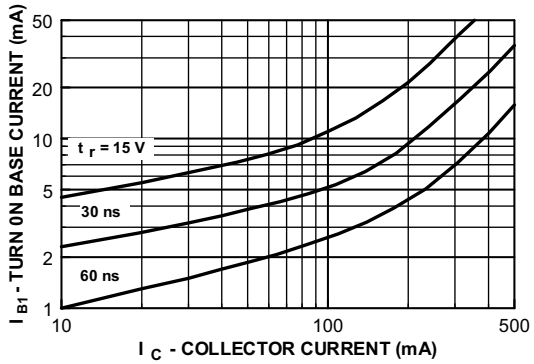


Figure 9. Rise Time vs. Collector and Turn-On Base Currents

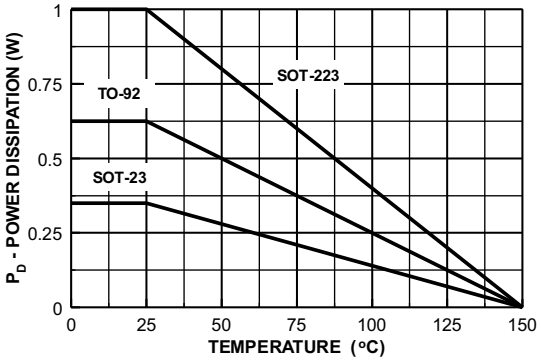


Figure 10. Power Dissipation vs. Ambient Temperature

Typical Performance Characteristics (f = 1.0 kHz)

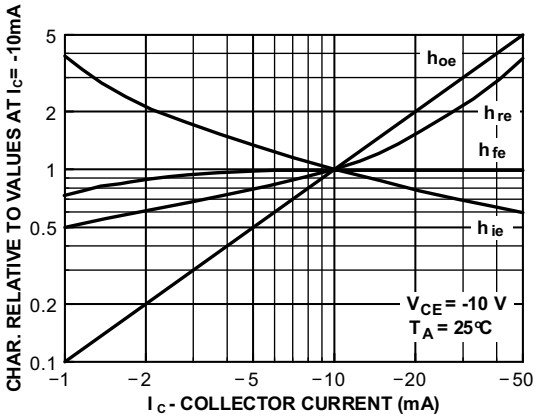


Figure 11. Common Emitter Characteristics

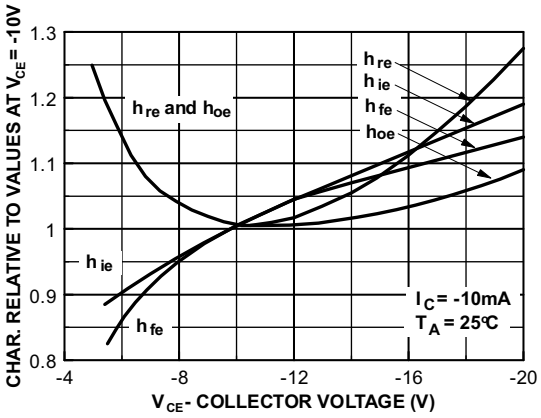


Figure 12. Common Emitter Characteristics

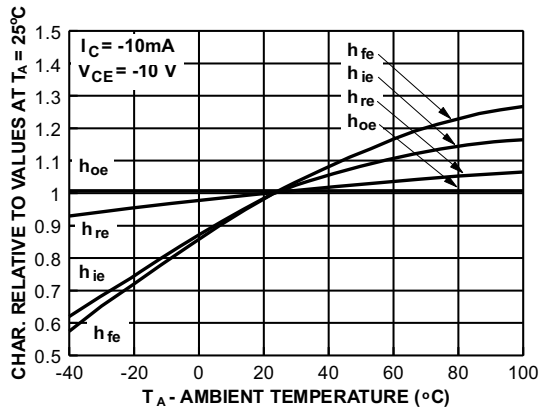
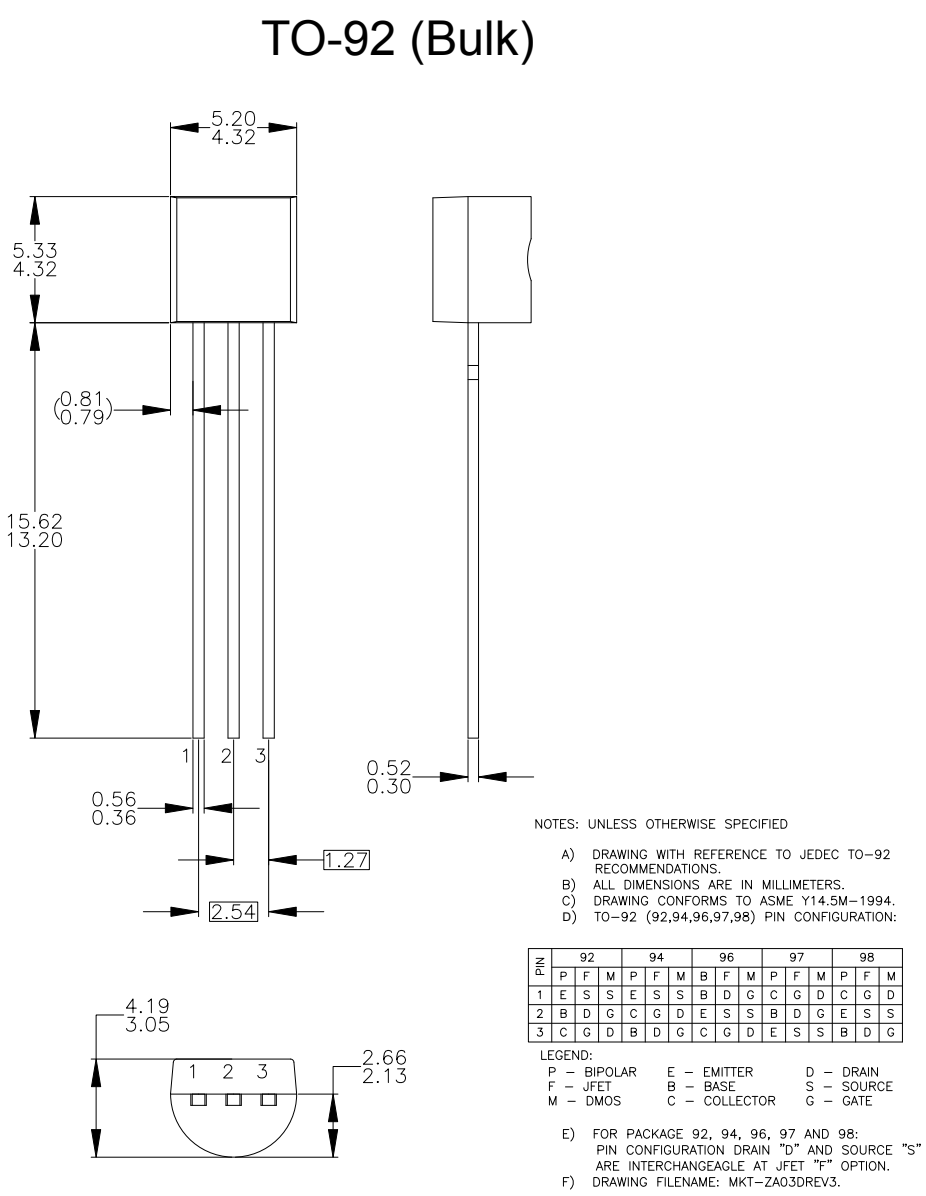


Figure 13. Common Emitter Characteristics

Physical Dimensions



PIN	92			94			96			97			98		
	P	F	M	P	F	M	B	F	M	P	F	M	P	F	M
1	E	S	S	E	S	S	B	D	G	C	G	D	C	G	D
2	B	D	G	C	G	D	E	S	S	B	D	G	E	S	S
3	C	G	D	B	D	G	C	G	D	E	S	S	B	D	G

Figure 14. 3-LEAD, TO92, JEDEC TO-92 COMPLIANT STRAIGHT LEAD CONFIGURATION (OLD TO92AM3) (ACTIVE)

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Physical Dimensions (Continued)

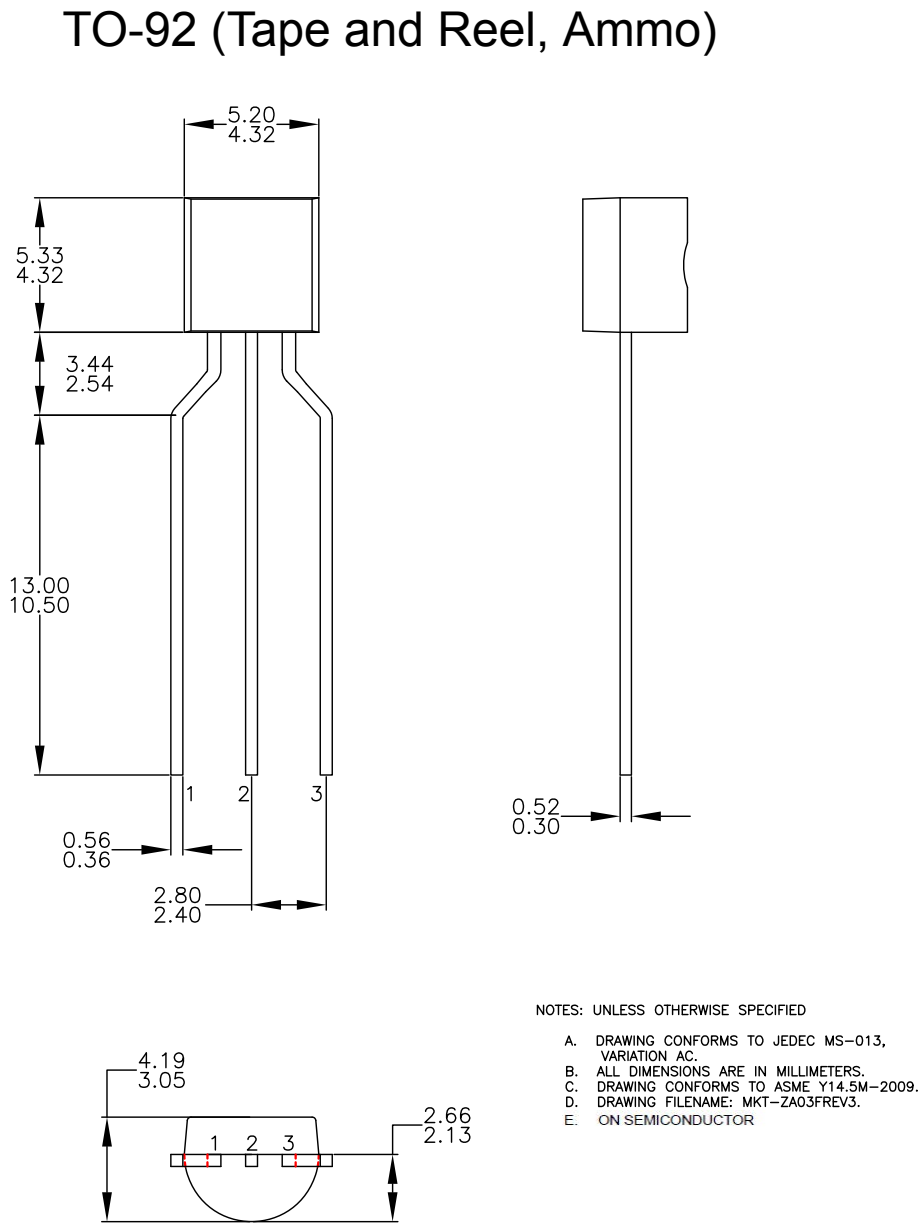

Figure 15. 3-LEAD, TO92, MOLDED 0.200 IN LINE SPACING LEAD FORM (J61Z OPTION) (ACTIVE)

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Physical Dimensions (Continued)

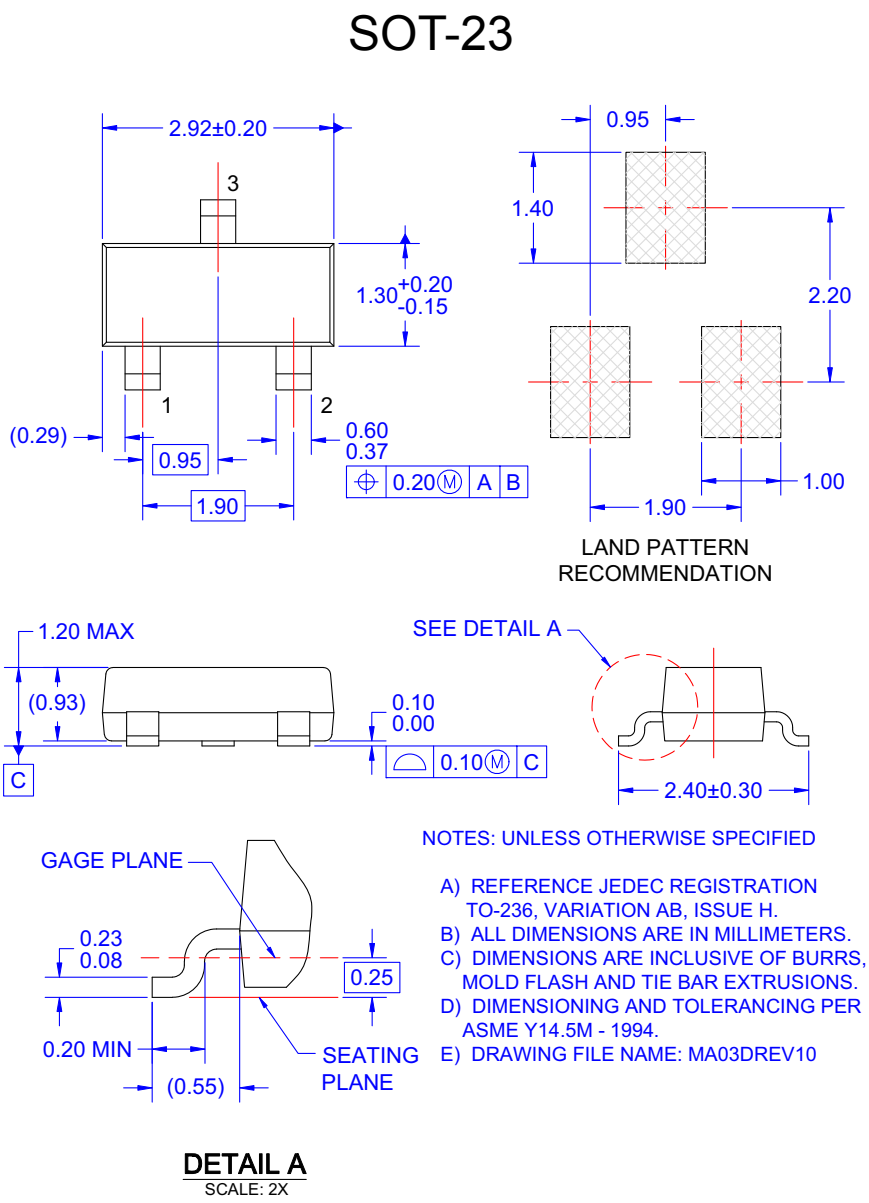

Figure 16. 3-LEAD, SOT23, JEDEC TO-236, LOW PROFILE (ACTIVE)

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Physical Dimensions (Continued)

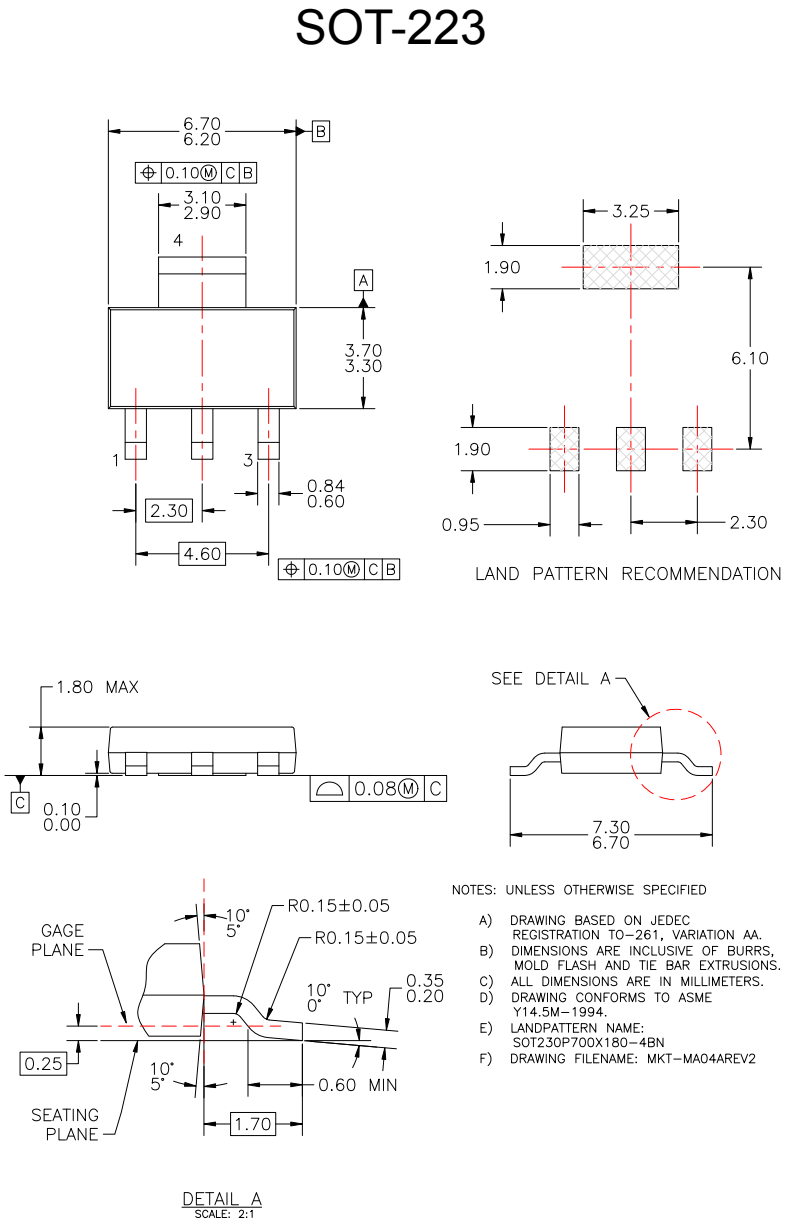

Figure 17. MOLDED PACKAGING, SOT-223, 4-LEAD (ACTIVE)

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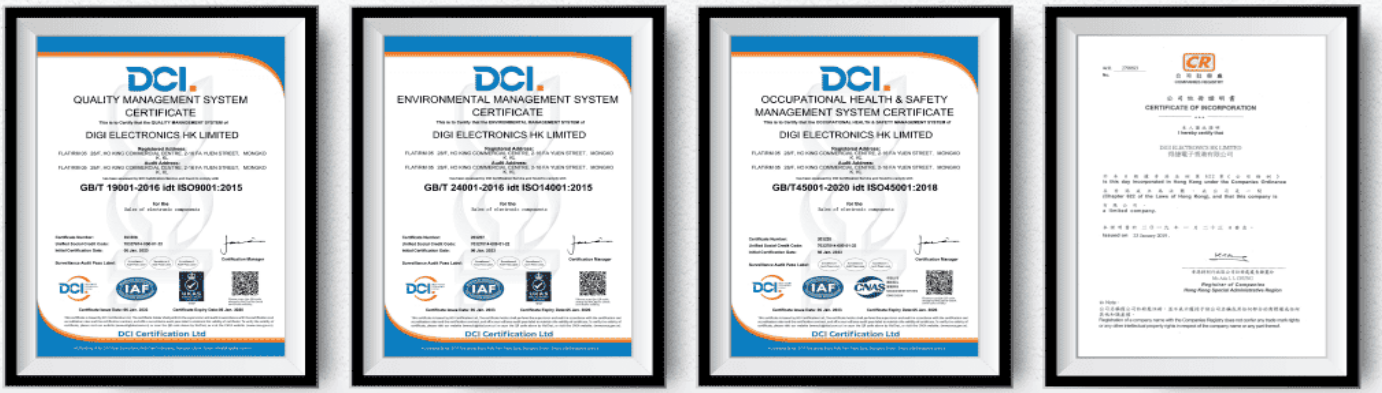

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